# SWITCHMODE™ Power Rectifier 45 V, 60 A

#### **Features and Benefits**

- Low Forward Voltage
- Low Power Loss/High Efficiency
- High Surge Capacity
- 175°C Operating Junction Temperature
- 60 A Total (30 A Per Diode Leg)
- Guard-Ring for Stress Protection
- This is a Pb-Free Device

#### **Applications**

- Power Supply Output Rectification
- Power Management
- Instrumentation

#### **Mechanical Characteristics:**

- Case: Epoxy, Molded
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Weight (Approximately): 1.9 Grams (TO-220)

4.3 Grams (TO-247)

- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Shipped 50 Units Per Plastic Tube for TO-220 and 30 Units Per Plastic Tube for TO-247

#### **MAXIMUM RATINGS**

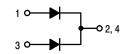
Please See the Table on the Following Page



#### ON Semiconductor®

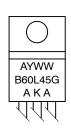
http://onsemi.com

## SCHOTTKY BARRIER RECTIFIERS 60 AMPERES, 45 VOLTS













B60L45 = Device Code A = Assembly Location

Y = Year
WW = Work Week
AKA = Polarity Designator
G = Pb-Free Device

#### **ORDERING INFORMATION**

Device	Package	Shipping
MBR60L45CTG	TO-220 (Pb-Free)	50 Units/Rail
MBR60L45WTG	TO-247 (Pb-Free)	30 Units/Rail

#### MAXIMUM RATINGS (Per Diode Leg)

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	45	V
Average Rectified Forward Current (Rated $V_R$ ) $T_C = 145^{\circ}C$ for MBR60L45CTG (Rated $V_R$ ) $T_C = 165^{\circ}C$ for MBR60L45WTG	I <sub>F(AV)</sub>	30	А
Peak Repetitive Forward Current (Rated V <sub>R</sub> , Square Wave, 20 kHz)	I <sub>FRM</sub>	60	Α
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)	I <sub>FSM</sub>	200	Α
Operating Junction Temperature (Note 1)	TJ	-65 to +175	°C
Storage Temperature	T <sub>stg</sub>	-65 to +175	°C
Voltage Rate of Change (Rated V <sub>R</sub> )	dv/dt	10,000	V/μs
ESD Ratings: Machine Model = C Human Body Model = 3B		> 400 > 8000	V

#### THERMAL CHARACTERISTICS

Maximum Thermal Resistance				°C/W
(MBR60L45CTG)	<ul><li>Junction-to-Case</li></ul>	$R_{ heta JC}$	1.9	
(MBR60L45WTG)	<ul><li>Junction-to-Case</li></ul>	$R_{ heta JC}$	0.59	

#### **ELECTRICAL CHARACTERISTICS** (Per Diode Leg)

Maximum Instantaneous Forward Voltage (Note 2) $ \begin{aligned} &(I_F=30~A,~T_C=25^\circ\text{C})\\ &(I_F=30~A,~T_C=125^\circ\text{C})\\ &(I_F=60~A,~T_C=25^\circ\text{C})\\ &(I_F=60~A,~T_C=125^\circ\text{C}) \end{aligned} $	VF	0.55 0.53 0.73 0.76	V
Maximum Instantaneous Reverse Current (Note 2) (Rated DC Voltage, T <sub>C</sub> = 25°C) (Rated DC Voltage, T <sub>C</sub> = 125°C)	İR	1.2 275	mA

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

<sup>1.</sup> The heat generated must be less than the thermal conductivity from Junction–to–Ambient:  $dP_D/dT_J < 1/R_{\theta JA}$ . 2. Pulse Test: Pulse Width = 300  $\mu$ s, Duty Cycle  $\leq$  2.0%.

#### **TYPICAL CHARACTERISTICS**

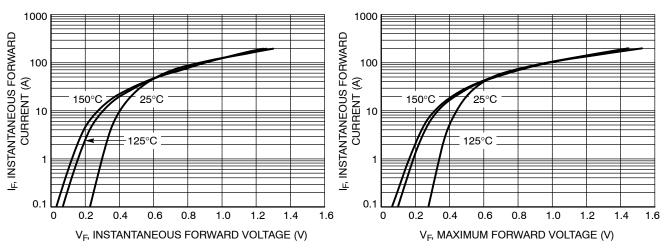


Figure 1. Typical Forward Voltage

Figure 2. Maximum Forward Voltage

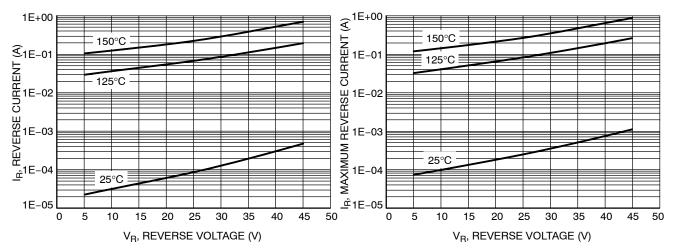


Figure 3. Typical Reverse Current

Figure 4. Maximum Reverse Current

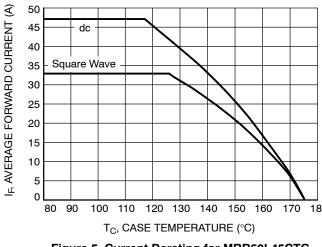


Figure 5. Current Derating for MBR60L45CTG

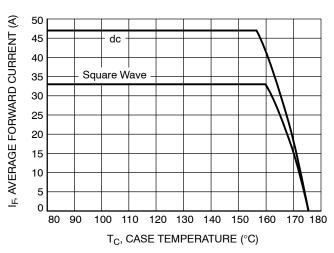


Figure 6. Current Derating for MBR60L45WTG

#### **TYPICAL CHARACTERISTICS**

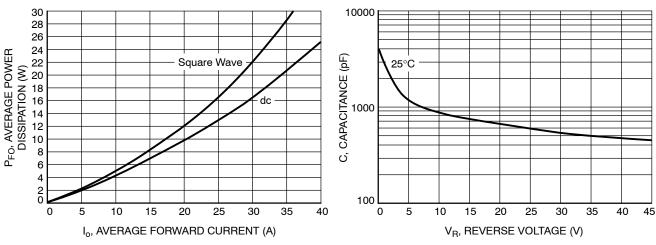


Figure 7. Forward Power Dissipation

Figure 8. Capacitance

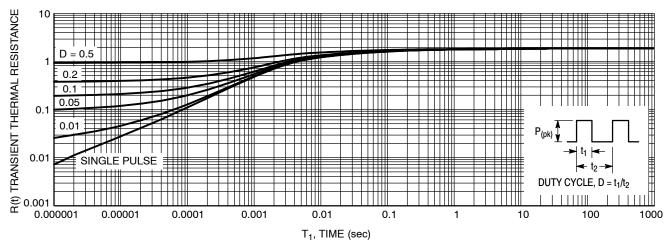


Figure 9. Thermal Response Junction-to-Case for MBR60L45CTG

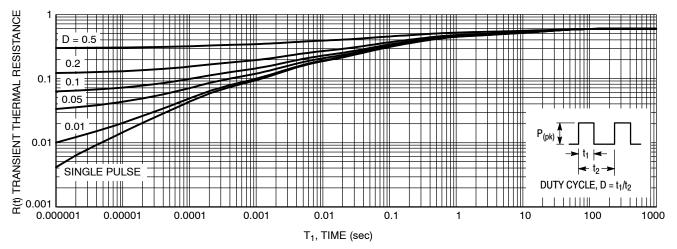
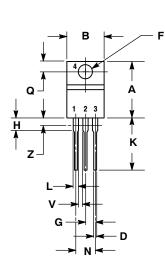
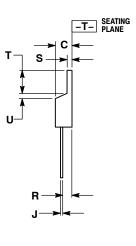


Figure 10. Thermal Response Junction-to-Case for MBR60L45WTG

#### **PACKAGE DIMENSIONS**

TO-220 CASE 221A-09 **ISSUE AF** 





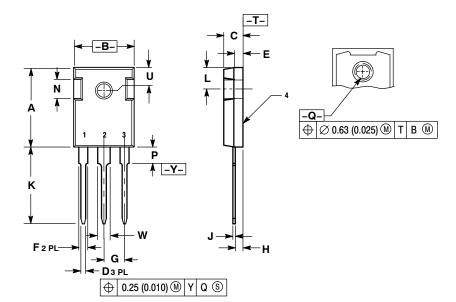
- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLING DIMENSION: INCH.
  3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.570	0.620	14.48	15.75
В	0.380	0.405	9.66	10.28
С	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.161	3.61	4.09
G	0.095	0.105	2.42	2.66
Н	0.110	0.155	2.80	3.93
J	0.014	0.025	0.36	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
٧	0.045		1.15	
Z		0.080		2.04

- STYLE 6:
  PIN 1. ANODE
  2. CATHODE
  3. ANODE
  4. CATHODE

#### PACKAGE DIMENSIONS

TO-247 CASE 340L-02 ISSUE E



#### NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: MILLIMETER.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
Α	20.32	21.08	0.800	8.30
В	15.75	16.26	0.620	0.640
С	4.70	5.30	0.185	0.209
D	1.00	1.40	0.040	0.055
Е	1.90	2.60	0.075	0.102
F	1.65	2.13	0.065	0.084
G	5.45 BSC		0.215 BSC	
Н	1.50	2.49	0.059	0.098
J	0.40	0.80	0.016	0.031
K	19.81	20.83	0.780	0.820
L	5.40	6.20	0.212	0.244
N	4.32	5.49	0.170	0.216
P		4.50		0.177
Q	3.55	3.65	0.140	0.144
U	6.15 BSC		0.242 BSC	
W	2.87	3.12	0.113	0.123

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